

## Excellent Integrated System Limited

Stocking Distributor

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[IXYS Corporation](#)

[DSI30-12A](#)

For any questions, you can email us directly:

[sales@integrated-circuit.com](mailto:sales@integrated-circuit.com)

## Standard Rectifier

$$V_{RRM} = 1200 \text{ V}$$

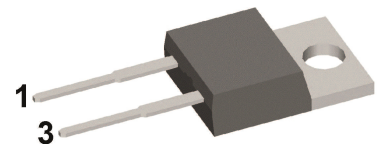
$$I_{FAV} = 30 \text{ A}$$

$$V_F = 1,25 \text{ V}$$

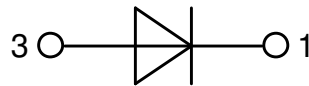
## Single Diode

Part number

**DSI30-12A**



Backside: cathode



### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

### Applications:

- Diode for main rectification
- For single and three phase bridge configurations

### Package: TO-220

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

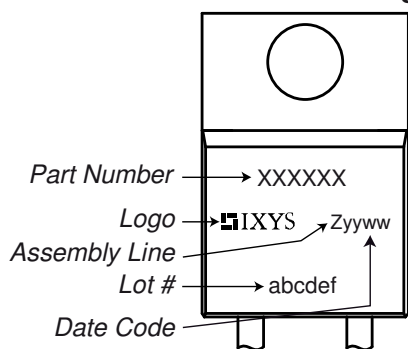
Rectifier				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
$V_{RSM}$	max. non-repetitive reverse blocking voltage				1300	V	
$V_{RRM}$	max. repetitive reverse blocking voltage				1200	V	
$I_R$	reverse current	$V_R = 1200\text{ V}$			40	$\mu\text{A}$	
		$V_R = 1200\text{ V}$			1,5	mA	
$V_F$	forward voltage drop	$I_F = 30\text{ A}$			1,29	V	
		$I_F = 60\text{ A}$			1,60	V	
		$I_F = 30\text{ A}$	$T_{VJ} = 150^\circ\text{C}$			1,25	V
		$I_F = 60\text{ A}$				1,66	V
$I_{FAV}$	average forward current	$T_C = 130^\circ\text{C}$ rectangular $d = 0.5$			30	A	
$V_{F0}$	threshold voltage	} for power loss calculation only			0,82	V	
$r_F$	slope resistance				14,1	m $\Omega$	
$R_{thJC}$	thermal resistance junction to case				0,9	K/W	
$R_{thCH}$	thermal resistance case to heatsink			0,50		K/W	
$P_{tot}$	total power dissipation				160	W	
$I_{FSM}$	max. forward surge current	$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$	$T_{VJ} = 45^\circ\text{C}$			300	A
		$t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$	$V_R = 0\text{ V}$			325	A
		$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$	$T_{VJ} = 150^\circ\text{C}$			255	A
		$t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$	$V_R = 0\text{ V}$			275	A
$I^2t$	value for fusing	$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$	$T_{VJ} = 45^\circ\text{C}$			450	A <sup>2</sup> s
		$t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$	$V_R = 0\text{ V}$			440	A <sup>2</sup> s
		$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}$	$T_{VJ} = 150^\circ\text{C}$			325	A <sup>2</sup> s
		$t = 8,3\text{ ms}; (60\text{ Hz}), \text{ sine}$	$V_R = 0\text{ V}$			315	A <sup>2</sup> s
$C_J$	junction capacitance	$V_R = 400\text{ V}; f = 1\text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$		10	pF	



# DSI30-12A

Package TO-220			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	RMS current	per terminal			35	A
$T_{VJ}$	virtual junction temperature		-40		175	°C
$T_{op}$	operation temperature		-40		150	°C
$T_{stg}$	storage temperature		-40		150	°C
<b>Weight</b>				2		g
$M_D$	mounting torque		0,4		0,6	Nm
$F_C$	mounting force with clip		20		60	N

### Product Marking



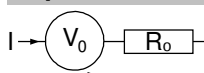
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSI30-12A	DSI30-12A	Tube	50	476390

Similar Part	Package	Voltage class
DSI30-08A	TO-220AC (2)	800
DSI30-08AS	TO-263AB (D2Pak) (2)	800
DSI30-08AC	ISOPLUS220AC (2)	800
DSI30-12AS	TO-263AB (D2Pak) (2)	1200
DSI30-12AC	ISOPLUS220AC (2)	1200
DSI30-16A	TO-220AC (2)	1600
DSI30-16AS	TO-263AB (D2Pak) (2)	1600

### Equivalent Circuits for Simulation

\* on die level

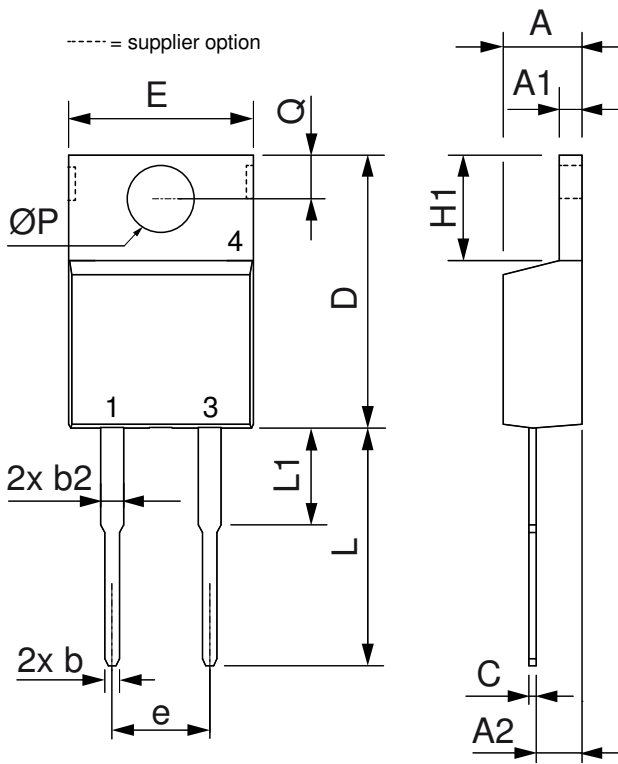
$T_{VJ} = 175\text{ °C}$



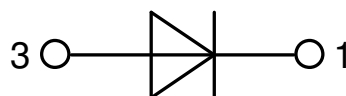
Rectifier

$V_{0\ max}$	threshold voltage	0,82	V
$R_{0\ max}$	slope resistance *	11	mΩ

**Outlines TO-220**



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.32	4.82	0.170	0.190
A1	1.14	1.39	0.045	0.055
A2	2.29	2.79	0.090	0.110
b	0.64	1.01	0.025	0.040
b2	1.15	1.65	0.045	0.065
C	0.35	0.56	0.014	0.022
D	14.73	16.00	0.580	0.630
E	9.91	10.66	0.390	0.420
e	5.08	BSC	0.200	BSC
H1	5.85	6.85	0.230	0.270
L	12.70	13.97	0.500	0.550
L1	2.79	5.84	0.110	0.230
ØP	3.54	4.08	0.139	0.161
Q	2.54	3.18	0.100	0.125



**Rectifier**

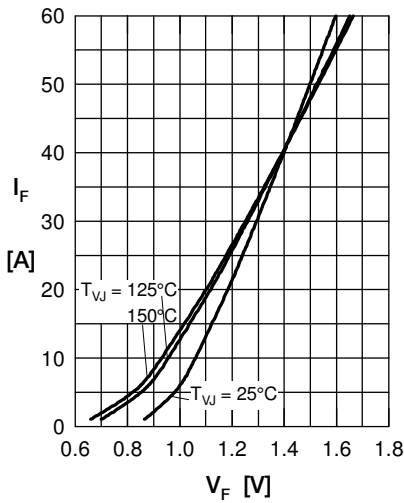


Fig. 1 Forward current versus voltage drop per diode

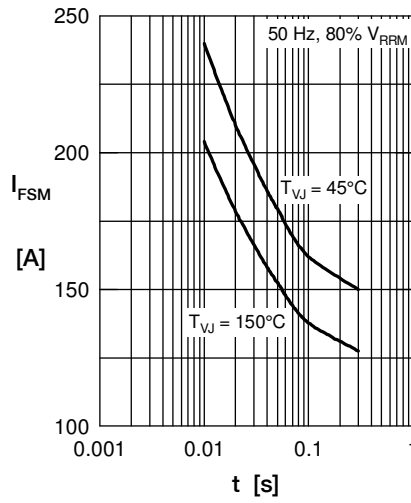


Fig. 2 Surge overload current

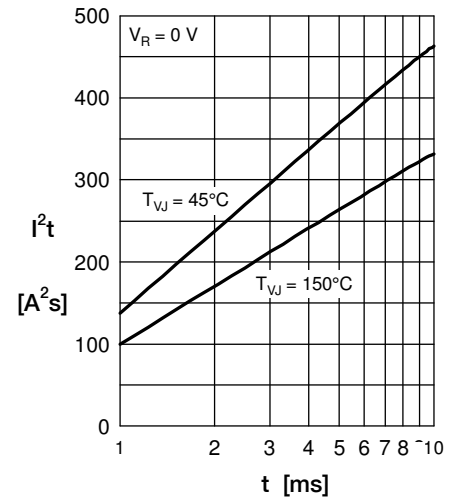


Fig. 3 I<sup>2</sup>t versus time per diode

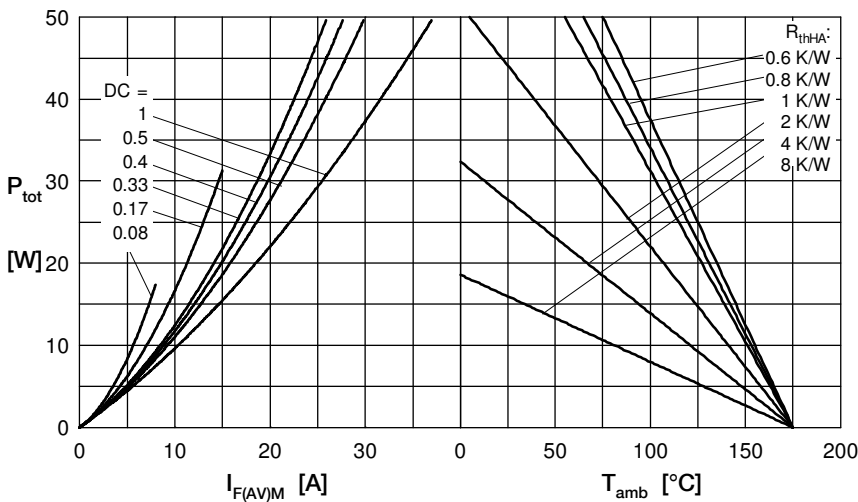


Fig. 4 Power dissipation vs. direct output current and ambient temperature

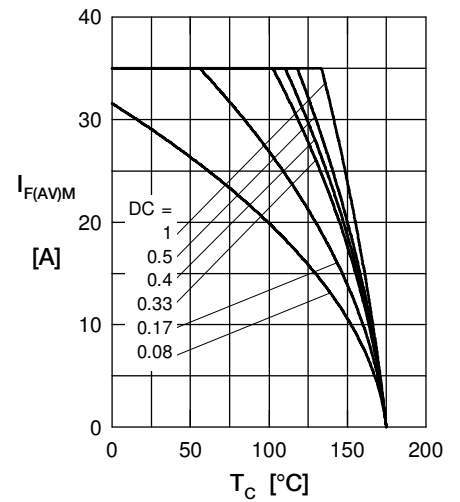


Fig. 5 Max. forward current vs. case temperature

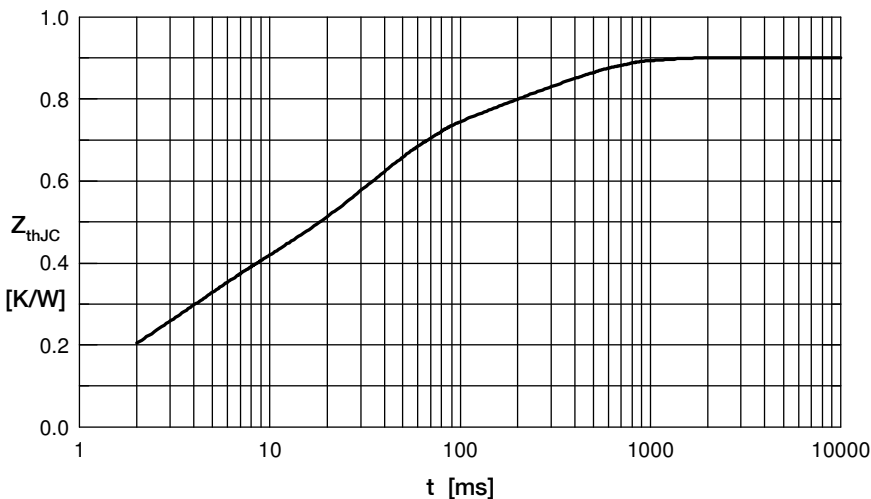


Fig. 6 Transient thermal impedance junction to case

Constants for  $Z_{thJC}$  calculation:

i	$R_{thi}$ (K/W)	$t_i$ (s)
1	0.03	0.0004
2	0.08	0.002
3	0.2	0.003
4	0.39	0.03
5	0.2	0.29